Design Smart Antenna by Microstrip Patch Antenna Array

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Abstract—Smart antennas have been studied extensively this decade because of its low profile structure and formidable rate, thereby creating new and improved services at lower costs. They are extremely compatible for embedded antennas in handheld wireless devices such as cellular phones, pagers etc. Because of its versatility, Smart antenna which is designed by planer array can be used to synthesize a required pattern that cannot be achieved with a single patch element.

Index Terms—Radiation patterns, Mobile communication, planar array, PCCAD 5.0 software etc.

I. INTRODUCTION

In high-performance aircraft, spacecraft, satellite and missile application, where size, weight, cost, performance, ease of installation, and aerodynamic profile are constraints, so low profile antennas may be required. Presently there are many other government and commercial applications, such as mobile, radio and wireless communications that have similar specifications .To meet these requirements “smart antennas” have been researched extensively. This has resulted in an increase in airtime usage and in the number of subscribers. Spatial processing is the central idea of smart antenna systems. Although it might seem that smart antennas have been recently discovered, they date back to World War II with the conventional Bartlett beamformer [1]. It is only of today’s advancement in powerful low-cost digital signal processors, general purpose processors (and ASICs—Application-Specific Integrated Circuits), as well as innovative software-based signal-processing techniques (algorithms), that smart antenna systems have received enormous interest worldwide. To approach the feature, design smart antenna by microstrip patch antenna array [2]. Quality factor (Q) of microstrip antennas is a very high. Quality factor can be reduced by increasing the dielectric substrate. But due to increasing thickness, unwanted power loss occurs by the surface wave. However, this surface waves can be minimized by the use of photonic bandgap structures [3].

Recent studies on microstrip antennas have primarily concentrated on the improvement of bandwidth and on the design of multifunction operations [4]–[7]. As a result, almost 100% bandwidth in terms of VSWR and dual-band operations for GSM900 and GSM1800 WLAN services have been success-fully accomplished and demonstrated.

II. MICROSTRIP ANTENNA AND FEEDING METHOD

A microstrip antenna is a metallic patch on top of a layer of dielectric substrate with a backing ground plane. It consists of four parts like a very thin flat metallic region often called patch, a dielectric substrate, a ground plane and a feed which supplies the element RF power.

Patch is a very thin flat metallic region .The longest dimension of the patch is typically about a third to a half of a free-space wavelength. So the patch starts to radiate. A commonly used dielectric substrate for microstrip antenna is polytetrafluorel (PTFE). A relative dielectric constant around 2.5 is typical. The ground plane is a printed circuit board. Monolithic Microwave Integrated Circuits (MMICs) combine microstrip antennas and associated circuitry in very compact form with applications at frequencies from 50 MHz to 100GHz.

There are four feeding mechanisms.

A. Microstrip-Line Feed

The microstrip line feed is easy to fabricate, simple to match by controlling the inset position and rather simple to model. However as the substrate thickness increases surface waves and spurious feed radiation increase, which for practical designs limit the bandwidth (typically 2-5%) [2].

B. Coaxial Probe Feed

Coaxial probe feeds (Fig. 2), where the inner conductor of the coax is attached to the radiation patch while the outer conductor is connected to the ground plane, are also used. The coaxial probe feed is also easy to fabricate and match and it has low spurious radiation. However, it also has narrow bandwidth and it is more difficult to model, especially for thick substrate [2].

C. Aperture -Coupled Feed

Both the microstrip feed line and the probe possesses inherent asymmetries which generate higher order modes which produce cross-polarized radiation. To overcome some of these problems, non contacting aperture coupling feeds,
as shown in Fig. 3, have been introduced. The aperture coupling is the most difficult of all four coupling methods to fabricate and it has narrow bandwidth. This coupling consists of two substrates separated by a ground plane. The aperture coupling consists of two substrates separated by a ground plane. On the bottom side of the lower substrate there is a microstrip feed line whose energy is coupled to the patch through a slot on the ground plane separating the two substrates. This arrangement allows independent optimization of the feed mechanism and the radiating element [2].

D. Proximity-Coupled Feed

In proximity-coupled feed method, two dielectric substrates are placed in such way that the feed line is between the two substrates and the radiating patch is on top of the upper substrate. The proximity-coupled method has the largest bandwidth (as high as 13%), is somewhat easy to model and has low spurious radiation. However its fabrication is somewhat more difficult [2].

E. Linearly Polarized Microstrip Antennas

Fig. 1 shows a patch antenna, in which the patch is rectangular and it is thus called rectangular patch antenna. When feed, a standing wave will occur as shown in Fig. 5, but some of the field will “leak out” around the edges of the patch. This is the so called fringing field. In the figure, we can see that the electric field on the left side outside the patch is going into the patch and on the other side leaving the patch. [8]
that case, interference problem in many users can be limited
in rectangular aperture type antenna. So they can direct the
main beam toward the pilot signal or SOI while suppressing
the antenna pattern in the direction of the interferers or
SNOIs. Consequently, for smart antennas, we use
rectangular patch antenna array.

Microstrip line is that which provides one free and
accessible surface on which solid state devices can be placed.
All electrical and electronic devices with high power output
commonly use conventional lines, such as coaxial lines or
waveguides, for power transmission. However the
microwave solid-state device is usually fabricated as a
semiconductor chip with a volume on the order of 0.008 to
0.08mm quake. The method of applying signals to the chips
and extracting output power from them is entirely different
from that used for vacuum tube devices. Microwaves
integrated circuits with microstrip lines are commonly used
with the chips. [10]

![Fig. 8. A microstrip transmission line](image)

Practical microstrip lines (shown in figure) have width to
height ratio w/h that are not necessarily much greater unity
and can vary over the interval 0.1< w/h <10. Typical heights
h are of the order of millimeter. Modes on microstrip lines
are only quasi-transverse electric and magnetic (TEM).
Radiation loss in microstrip lines is a problem. However the
use of thin, high-dielectric materials considerably reduces
the radiation loss of the microstrip. The characteristic
impedance of a microstrip line is a function of the strip-line
width, the strip-line thickness, the distance between the line
and the ground plane and the homogeneous dielectric
constant of the board material. Here $\varepsilon_r$ = dielectric constant

$$Z_0 = \frac{60\varepsilon_r}{\ln(4h)}$$  \hspace{1cm} (1)

IV. METHODS OF MODELING

Three methods of analysis are commonly used to evaluate
microstrip antenna (MSA) parameters [11], [12]. These are:
Transmission line model, cavity model, and full wave
analysis.

A. Transmission Line Model of Microstrip Patch

The transmission-line model is the easiest of all, it gives
good physical insight. Basically the transmission line model
represents the microstrip patch antenna by two slots,
separated by a low impedance ($Z_0$) transmission line of
length L [9], [11].

![Fig. 9. Transmission line model of patch antenna](image)

The voltage distributions at the edges of the microstrip
patch antenna operation in the $TM_{10}$ dominant mode (or
$TM_{50}$) can be obtained by using a transmission line model.
For $TM_{10}$ (or $TM_{30}$) mode of the microstrip patch, there is
no variation of fields in the y direction. The field distribution
is identical to that of a uniform transmission line of
characteristic impedance $Z_0$ and $V_{ph}$. The fringing fields
associated with edges 01 and 23 of the patch are taken into
account by $Z_0$ and $V_{ph}$. The fringing fields associated with
edges 02 and 13 are represented by lumped admittances $Y_e$
(edge conductance) connected at the two ends [9].

B. Transmission Line Model of Microstrip Patch for Edge
Admittance

Edge admittance is given by,

$$Y_e = G_e + jB_e$$  \hspace{1cm} (2)

where $G_e = \omega C_e$, $G_e$, $B_e$, $C_e$ are the edge conductance, edge
susceptance and edge capacitance respectively. The edge
conductance accounts for the power radiated at the radiating
edges (or open ends).The edge susceptance accounts for the
fringing electric field (and hence the fringing capacitance at
the open end) [2].

C. Transmission Line Model of Microstrip Patch for Edge
Capacitance

The edge capacitance, $C_e$ is represented in terms of an
equivalent line length extension as shown in the following
figure:

![Fig. 10. Transmission line model for microstrip Patch: Edge capacitance](image)

From the theory of open ended transmission line, the edge
susceptance of microstrip patch can be expressed as [9], [11].

$$B_0 = \omega C_0 = Y_0 \tan(\beta \Delta l)$$  \hspace{1cm} (3)

where $Y_0$, $\beta$ and $\Delta l$ are the characteristic admittance, phase
constant and incremental length of the patch due to fringing
effect respectively.
If \( \beta \Delta l \ll 1 \) or \( \Delta l \ll \lambda \)

Then the edge capacitance can be approximated as

\[
C_B = \frac{\Delta l}{v_p \pi_0}
\]

(4)

where \( v_p = \frac{\omega}{k} \), \( v_p \) is the phase velocity and \( Z_0 \) is the characteristic impedance.

A. Normalized Length vs. Normalized Width Curve

Because of the fringing effect, electrically the patch of the microstrip antenna looks greater than its physical dimension as shown in Fig. 10. The dimension of the patch along its length have been extended on each end side by a distance \( \Delta l \), which is a function of dielectric constant, \( \varepsilon_r \) and width to height ration \((w/h)\) and can be expressed as \[2\].

Normalized length,

\[
\frac{\Delta l}{h} = 0.412 \left( \varepsilon_{\text{eff}} +0.3 \left( \frac{w}{h} + 0.264 \right) \right)
\]

\[
\left( \varepsilon_{\text{eff}} -0.258 \left( \frac{w}{h} + 0.8 \right) \right)
\]

(5)

The Normalized Length vs. Normalized Width Curve is drawn in Fig. 11. For various values of dielectric constant, \( \varepsilon_r \).

From Fig. 11, it is seen that for a fixed normalized width, the normalized length increases with the decrease in dielectric constant and for a fixed dielectric constant the normalized length increases with the increase in normalized width.

B. Calculation of Edge Conductance

The edge conductance accounts for the power radiated at the radiating edges and can be evaluated using the equivalent magnetic current model for fringing field edges. In order to calculate the edge conductance the expressions of electric field and magnetic field are required.

In order to determine the edge or radiation conductance approximation, three ranges are taken into account which is given below \[13\].

Range 1: \( \frac{w}{\lambda_0} \ll 1 \), the edge conductance becomes

\[
G_r = \frac{1}{90} \left( \frac{w}{\lambda_0} \right)^2
\]

(6)

Range 2: \( 35\lambda_0 \leq w \leq 2\lambda_0 \), the edge conductance becomes

\[
G_r = \frac{1}{120} \times \frac{w}{\lambda_0} - \frac{1}{60\pi}
\]

(7)

Range 3: \( \frac{w}{\lambda_0} \gg 1 \quad w \rightarrow \alpha \)

The edge conductance becomes

\[
G_r = \frac{1}{120} \frac{w}{\lambda_0}
\]

(8)

Using the above three ranges the edge conductance, \( G_r \) is plotted as a function of width to free space wavelength ration, \( \frac{w}{\lambda_0} \) as given below:

C. Expressions of E-Field and H-Field Of N-Elements Linear Array

Antenna array is used to improve performances such as gain, directivity etc. In the case of patch antenna array, it can be used to scan the beam of an antenna system and perform various other functions which would be difficult with any one single element. Fig. 15 shows a rectangular patch antenna array of n-elements separated from each other by a distance \( d \).

D. Drawback of Linear Array

Linear arrays lack the ability to scan in 3-D space, and since it is necessary for portable devices to scan the main beam in any direction of \( \theta \) (elevation) and \( \phi \) (azimuth),
planner arrays are more attractive for these mobile devices, so we can design $MN \times N$ identical elements in the $xy$-plane as shown in Fig. 16.

E. $M \times N$ Planar Array

![Design of a $M \times N$ planar array with rectangular patches.](source: [15])

D. Design and Parameter Calculation

The design procedure of patch antenna assumes that the specified information includes the dielectric constant of the substrate ($\varepsilon = 2.2$), the resonant frequency ($f_r = 10^{10}$Hz) and the height of the substrate ($h = 2.93\text{mm}$). The necessary equations to design patch antenna [14]

The width of the patch for effective radiation can be expressed as

$$W = \frac{1}{2f_r\sqrt{\mu_0\varepsilon_0}} \sqrt{\frac{2}{\varepsilon_r + 1}} = \frac{y_w}{2f_r\sqrt{\varepsilon_r + 1}} = \frac{3 \times 10^4}{2 \times 10^{10}} \sqrt{\frac{2}{2.2 + 1}} = 11.8585 \pm 11.9\text{mm}$$

The effective refractive index can be expressed as

$$n_{eff} = \frac{\varepsilon_{r} + 1}{2} + \frac{\varepsilon_{r} - 1}{2} \left[ 1 + \frac{h}{W_w} \right]^{-1/2}$$

$$= \frac{2.2 + 1}{2} + \frac{2.2 - 1}{2} \left[ 1 + \frac{1}{2.93\text{mm}} \right]^{-0.5} = 1.9013$$

The extension of length of each side can be expressed as

$$\Delta l = 0.412 \times \left( n_{eff} + 0.3 \right) \frac{W}{h} + 0.264 \times h$$

$$= 0.412 \times \left( 1.9013 + 0.3 \right) \frac{W}{h} + 0.264 \times h$$

$$= 1.20 + \frac{1.1992}{12.93\text{mm}} + 0.264 \times \frac{1.1992 + 0.8}{2.2 - 0.258} \times 2.93\text{mm} = 1.4\text{mm}$$

The actual length of the patch can be expressed as

$$L = \frac{1}{2f_r\sqrt{\mu_0\varepsilon_0}} \times 2\Delta l = \frac{3 \times 10^4}{2 \times 10^{10}} \times 1.9013 - 2 \times 1.4\text{mm}$$

$$= 8\text{mm}$$

Effective length of the patch can be expressed as

$$L_{eff} = \frac{1}{2f_r\sqrt{\mu_0\varepsilon_0}} = \frac{y_w}{2f_r\sqrt{\varepsilon_0}} = \frac{3 \times 10^4}{2 \times 10^{10}} \times 1.9013$$

$$= 10.9\text{mm}$$

Because of the odd field distribution between the radiating slots for the dominant $TM_{010}$ mode.

By numerically calculation, the input impedance of the patch can be expressed as

$$Z_i = \frac{1}{2(G_1 + G_2)} = 231.349\Omega$$

Length of the impedance inverter

$$\frac{\lambda_0}{4} = \frac{\lambda}{\varepsilon_0} = 5.06\text{mm}$$

Width of the impedance inverter,

$$W = h \left( \frac{z_0}{z_{r\text{eff}}} - 2 \right) = 2.2\text{mm}$$

The characteristic impedance,

$$Z_0 = \sqrt{Z_iZ_r} = \sqrt{231.349 \times 50} = 107.552\Omega$$

where, $Z_2$ is the probe impedance $= 50\Omega$.
E. RADIATION PATTERNS OF E-FIELD AND H-FIELD

A. Variation of Radiation Pattern Due To Change of Relative Dielectric Constant

Fig. 18 shows the effect of the dielectric constant of the substrate of the rectangular microstrip antenna on its radiation pattern. Fig. 18(a) shows the radiation pattern with the parameter $h = 2.93$ mm, $f_r = 10$ GHz & $\varepsilon_r = 2.2$. Fig. 18(b) shows the radiation pattern with the parameter $h = 2.93$ mm, $f_r = 10$ GHz & $\varepsilon_r = 5$.

B. Variation of Radiation Pattern Due To Change of Height ($H$)

Fig. 19 shows the effect of the height of the rectangular microstrip antenna on its radiation pattern. Fig. 19(a) shows the radiation pattern with the parameter $h = 2.93$ mm, $f_r = 10$ GHz & $\varepsilon_r = 5$. Fig. 19(b) shows the radiation pattern with the parameter $h = 5$ mm, $f_r = 10$ GHz & $\varepsilon_r = 5$.

C. Radiation Pattern of Single Patch Antenna

Radiation pattern of E-field and H-field for distance $r=80$ cm are shown in Fig. 20(a) and for $r=115$ cm are shown in Fig. 20(b).
D. Radiation Pattern Of Two Element Linear Patch Antenna

Radiation pattern of E-field and H-field for distance $r=80\text{cm}$ are shown in Fig. 21. (a) and for $r=115\text{cm}$ are shown in Fig. 21. (b)

From above figures we can observe that, for single patch antenna, radiation pattern spread with increases distance. But for two element linear array radiation pattern is sharp than single patch antenna and hence that radiation pattern not spread with increases distance.

E. Radiation Pattern of $2 \times 2$ Planer Array Antenna

From Fig. 21 and Fig. 22 we can observe that, for $2 \times 2$ planer array antenna’s main lobes are sharper than linear array antenna. Moreover, radiation pattern is not dependent on distance for a certain limit. So, planner array is more suitable for smart antenna.

F. Radiation Patterns Obtained Using Pccad 5.0 Software

PCCAD 5.0 is useful software for obtaining both polar and 3-D radiation pattern. Moreover various parameters such as bandwidth, efficiency, directivity, 3-dB beam width can be calculated. The radiation pattern of E-field and H-field for single patch element using PCCAD 5.0 software is shown in Fig. 23.

The following parameters are obtained using PCCAD 5.0 software:

| TABLE I: PARAMETERS USING PCCAD 5.0 SOFTWARE |
|-----------------|----------------|
| Bandwidth       | 99%            |
| Efficiency      | 99%            |
| Directivity     | 6.7            |
| Beamwidth       | 76.6 degree for H-plane |

The 3-D radiation pattern of a single patch element using PCCAD 5.0 software is shown in Fig. 24.
The radiation pattern of E-field for two element patch array using PCCAD 5.0 software is shown in Fig. 25.

The 3-D radiation pattern of two elements patch array using PCCAD 5.0 software is shown in Fig. 26.

The radiation pattern of E-field for four element linear array using PCCAD 5.0 software is shown in Fig. 27.
The 3-D radiation pattern of four element linear array using PCCAD 5.0 software is shown in Fig. 28.
The radiation pattern of E-field for $2 \times 2$ planer array[12] using PCCAD 5.0 software is shown in Fig. 29.
The 3-D radiation pattern of $2 \times 2$ planer array using PCCAD 5.0 software is shown in Fig. 30.
TABLE III: PARAMETERS USING PCCAD 5.0 SOFTWARE

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<tr>
<td>Directivity</td>
<td>12.6</td>
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<tr>
<td>3-dB Beamwidth</td>
<td>12.9 degree for E-plane</td>
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Table IV: Parameters Using PCCAD 5.0 Software

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<tr>
<td>Directivity</td>
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<tr>
<td>3-dB Beamwidth</td>
<td>28.1 degree for E-plane</td>
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F. CONCLUSION

Therefore we mention that, for $2 \times 2$ planer array antenna’s main lobes are sharper than linear array antenna. Moreover, radiation pattern is not dependent on distance for a certain limit. So, planner array is more suitable for smart antenna. For highly versatile uses $4 \times 4$ or $8 \times 8$ planer is necessary to determine the array configuration is most attractive for a wireless device in a Mobile Ad hoc NETwork (MANET) [15]. Limitation of this system is that it tends to increase the cost and the complexity of the hardware implementation, and the other is that it increases the convergence time for the adaptive algorithms, thereby reducing valuable bandwidth.

REFERENCES


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